TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG100J101H

High Power Switching Applications Motor Control Applications

- Integrates inverter & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.

• High speed type IGBT : $V_{CE (sat)} = 2.5 \text{ V (Max.)}$

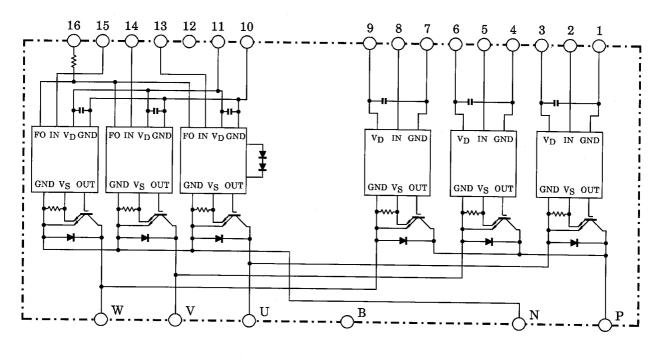
 $t_{\text{off}} = 3.0 \ \mu \text{s} \ (\text{Max.})$

 $t_{rr} = 0.30 \mu s \text{ (Max.)}$

• Outline: TOSHIBA 2-110A1A

• Weight: 520 g

Equivalent Circuit



- 1. GND (U)
- 2. IN (U)
- 3. V_D(U)
- 4. GND (V)
- 5. IN (V)
- 6. V_D(V)

- 7. GND (W)
- 8. IN (W)
- 9. V_D(W)
- 10. GND (L)
- 11. V_D(L)
- 12. OPEN

- 13. IN(X)
- 14. IN (Y)
- 15. IN(Z)
- 16. FO

Maximum Ratings ($T_j = 25$ °C)

| Stage | Characteristic | Condition | Symbol | Ratings | Unit |
|----------|-----------------------------|------------------------------|------------------|------------|------|
| Inverter | Supply voltage | P-N power terminal | V _{CC} | 450 | V |
| | Collector-emitter voltage | _ | V _{CES} | 600 | V |
| | Collector current | T _C = 25°C, DC | Ic | 100 | Α |
| | Forward current | T _C = 25°C, DC | lF | 100 | Α |
| | Collector power dissipation | T _C = 25°C | PC | 300 | W |
| | Junction temperature | _ | Tj | 150 | °C |
| Control | Control supply voltage | V _D -GND terminal | V _D | 20 | V |
| | Input voltage | IN-GND terminal | V _{IN} | 20 | V |
| | Fault output voltage | FO-GND (L) terminal | V _{FO} | 20 | V |
| | Fault output current | FO sink current | I _{FO} | 14 | mA |
| Module | Operating temperature | _ | TC | -20 ~ +100 | °C |
| | Storage temperature range | _ | T _{stg} | -40 ~ +125 | °C |
| | Isolation voltage | AC 1 minute, | V _{ISO} | 2500 | V |
| | Screw torque | M5 | _ | 3 | N·m |

Electrical Characteristics ($T_j = 25$ °C)

a. Inverter Stage

| Characteristic | Symbol | Test Condition | | Min | Тур. | Max | Unit |
|------------------------------|---------------------------------------|---|------------------------|-----|------|-----|------|
| Collector cut-off current | I _{CEX} V _{CE} = 60 | Vo= = 600 V | T _j = 25°C | _ | _ | 1 | mA |
| Conector curent | | VCE − 000 V | T _j = 125°C | 1 | - | 20 | |
| Collector-emitter saturation | V | VD = 15 V, 10 = 100 A | T _j = 25°C | _ | 2.0 | 2.5 | V |
| voltage | V _{CE} (sat) | | T _j = 125°C | _ | 2.0 | _ | |
| Forward voltage | V _F | I _F = 100 A | | ı | 2.1 | 3.3 | V |
| | t _{on} | $V_{CC} = 300 \text{ V}, I_C = 100 \text{ A}$ $V_D = 15 \text{ V}, V_{IN} = 15 \text{ V} \leftrightarrow 0 \text{ V}$ | | ı | 1.0 | 2.0 | · μs |
| Switching time | t _{off} | | | 1 | 1.7 | 3.0 | |
| Ownering time | t _f | Inductive load | (Note 1) | 1 | 0.2 | 0.5 | μο |
| | t _{rr} | | (NOTE 1) | | 0.1 | 0.3 | |



b. Control Stage $(T_j = 25^{\circ}C)$

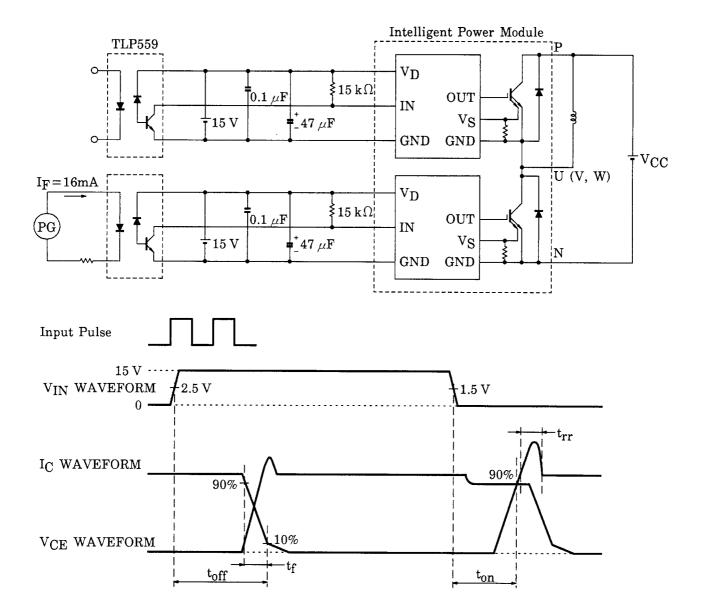
| Characteristic | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-------------|-----------------------|--|-----|------|------|---------------------------------------|
| Control circuit current | High side | I _{D (H)} | V _D = 15 V | _ | 8 | _ | mA |
| | Low side | I _{D (L)} | ND - 19 V | | 24 | _ | IIIA |
| Input-on signal voltage | | V _{IN (on)} | V _D = 15 V, I _C = 100 mA | | 1.5 | 1.7 | V |
| Input-off signal voltage | | V _{IN (off)} | V _D = 15 V, I _C = 100 mA | | 2.5 | 2.8 | V |
| Fault output current | Protection | I _{FO (on)} | V - 45 V | 8 | 10 | 12 | mA |
| | Normal | I _{FO (off)} | V _D = 15 V | | _ | 1 | mA |
| Over current protection trip level | Inverter | ОС | V _D = 15 V, T _j = 125°C | 160 | 200 | _ | Α |
| Short current protection trip level | Inverter | SC | V _D = 15 V, T _j = 125°C | 240 | 300 | _ | А |
| Over current cut-off time | | t _{off (OC)} | V _D = 15 V | _ | 5 | _ | μs |
| Over | Trip level | ОТ | Constant and | 110 | 118 | 125 | °C |
| temperature protection | Reset level | OTr | Case temperature | _ | 98 | _ | |
| Control supply under voltage protection | Trip level | UV | 11.0 | | 12.0 | 12.5 | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |
| | Reset level | UVr | _ | _ | 12.5 | _ | V |
| Fault output pulse width | | t _{FO} | V _D = 15 V | 1 | 2 | 3 | ms |

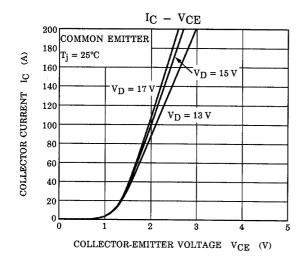
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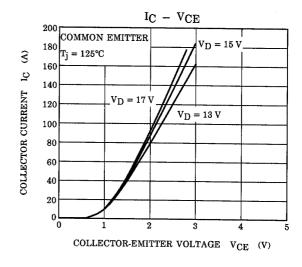
c. Thermal Resistance ($T_j = 25$ °C)

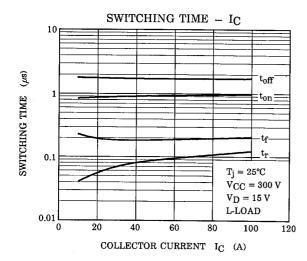
| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------------|-----------------------|---------------------|-----|------|-------|------|
| Junction to case thermal resistance | D., | Inverter IGBT stage | _ | _ | 0.418 | °C/W |
| ounction to case thermal resistance | R _{th (j-c)} | Inverter FRD stage | _ | _ | 1.000 | |
| Case to fin thermal resistance | R _{th (c-f)} | Compound is applied | _ | 0.05 | _ | °C/W |

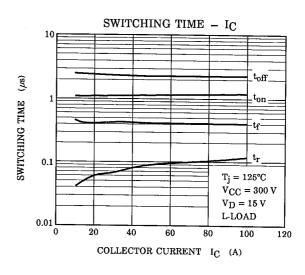
Note 1: Switching time test circuit & timing chart

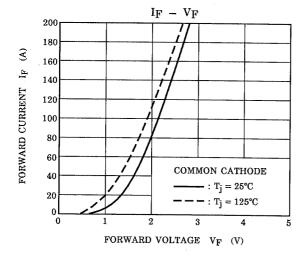


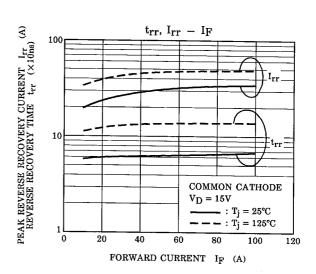


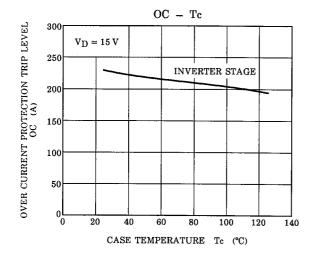


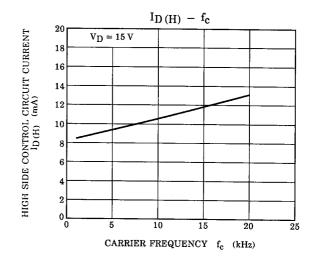


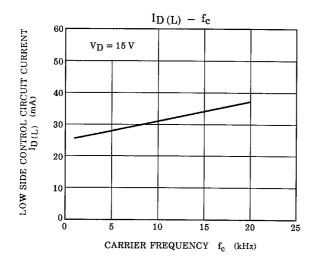


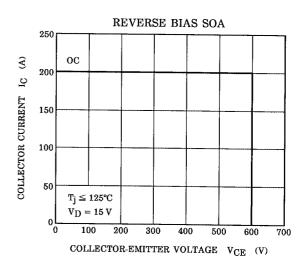


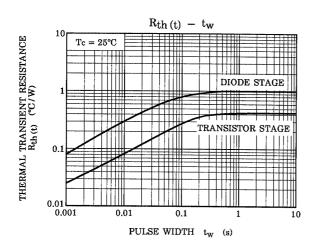






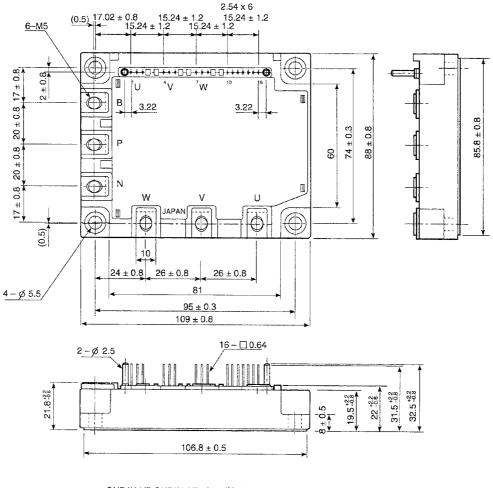






Package Dimensions: TOSHIBA 2-110A1A

Unit: mm



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